

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





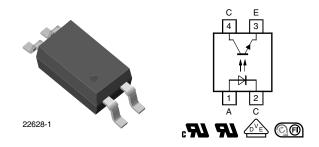


COMPLIANT



Vishay Semiconductors

Optocoupler, Phototransistor Output, Single Channel, Half Pitch Mini-Flat Package



DESCRIPTION

The TCMT111X series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin package.

APPLICATIONS

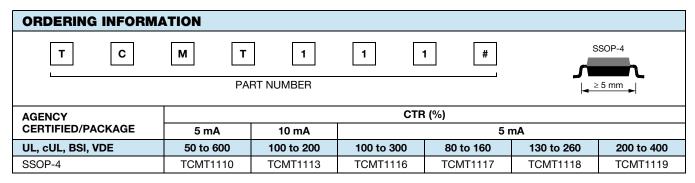
- Programmable logic controllers
- Modems
- Answering machines
- · General applications

FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- · Current transfer ratio (CTR) selected into groups
- · Low temperature coefficient of CTR
-
- Wide ambient temperature range
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



- UL1577, file no. E76222, double protection
- cUL component acceptance service no. 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5)
- FIMKO: FI EN 60950-1:2006
- BSI: BS EN60065:2002 BS EN60950-1:2006
- CQC GB 8898-2011, GB 4943.1-2011 (suitable for installation altitude below 2000 m)



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V _R	6	V		
Forward current		I _F	50	mA		
Forward surge current	t _P ≤ 10 μs	I _{FSM}	1.5	Α		
Power dissipation		P _{diss}	80	mW		
Junction temperature		Tj	125	°C		



www.vishay.com Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
OUTPUT								
Collector emitter voltage		V _{CEO}	70	V				
Emitter collector voltage		V _{ECO}	7	V				
Collector current		I _C	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA				
Power dissipation		P _{diss}	150	mW				
Junction temperature		Tj	125	°C				
COUPLER								
Total power dissipation		P _{tot}	230	mW				
Operating ambient temperature range		T _{amb}	-40 to +110	°C				
Storage temperature range		T _{stg}	-40 to +125	°C				
Soldering temperature (1)		T _{sld}	260	°C				

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Wave soldering three cycles are allowed. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT	INPUT						
Forward voltage	I _F = 5 mA	V_{F}	-	1.08	1.4	V	
Junction capacitance	V _R = 0, f = 1 MHz	Cj	-	8	-	pF	
OUTPUT							
Collector emitter voltage	I _C = 100 μA	V _{CEO}	70	-	-	V	
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7	-	-	V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0$	I _{CEO}	-	-	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}	-	0.1	0.3	V	
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c	-	100	-	kHz	
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCMT1110	CTR	50	-	600	%
	V _{CE} = 5 V, I _F = 10 mA	TCMT1113	CTR	100	-	200	%
		TCMT1114	CTR	160	-	320	%
	V _{CE} = 5 V, I _F = 5 mA	TCMT1117	CTR	80	-	160	%
		TCMT1118	CTR	130	-	260	%
		TCMT1119	CTR	200	ı	400	%



SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _d	-	4	-	μs
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _r	-	5.5	-	μs
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _f	-	7	-	μs
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _s	-	1.5	-	μs
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{on}	-	9.5	-	μs
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{off}	-	8	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{on}	-	3	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{off}	-	20	-	μs

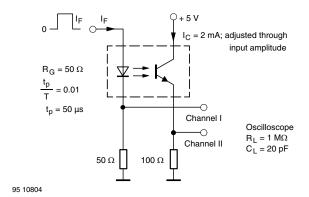


Fig. 1 - Test Circuit, Non-Saturated Operation

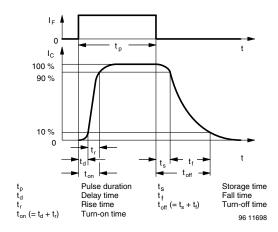


Fig. 3 - Switching Times

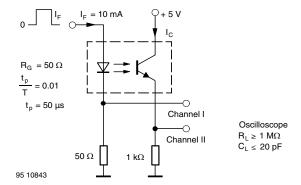


Fig. 2 - Test Circuit, Saturated Operation



SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification (according to IEC 68 part 1)			55/110/21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	40 % to 60 % RH, AC test of 1 min	V _{ISO}	3750	V_{RMS}		
Maximum transient isolation voltage		V _{IOTM}	6000	V		
Maximum repetitive peak isolation voltage		V _{IORM}	707	V		
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹	Ω		
Isolation resistance (under fault conditions)	$V_{IO} = 500 \text{ V}, T_{amb} = T_{SI}$	R _{IO}	10 ⁹	Ω		
Output safety power		P _{SO}	350	mW		
Input safety current		I _{SI}	200	mA		
Input safety temperature		T _{SI}	175	°C		
Apparent charge test voltage (method A)	V_{IORM} x 1.6 = V_{PR} , type and sample test t_m = 60 s, partial discharge < 5 pC	V_{PR}	1132	V _{peak}		
Apparent charge test voltage (method B)	V_{IORM} x 1.875 = V_{PR} , 100 % production test with t_m = 1 s, partial discharge < 5 pC	V_{PR}	1326	V _{peak}		
Creepage distance			≥ 5	mm		
Clearance distance			≥ 5	mm		
Insulation thickness		DTI	≥ 0.4	mm		
Environment (pollution degree in accordance to DI	N VDE 0109)		2			

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

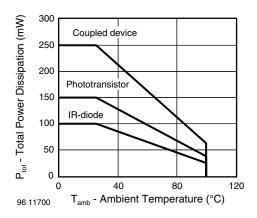


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

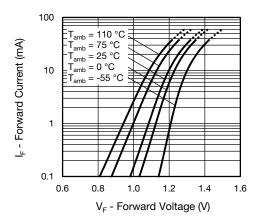


Fig. 5 - Forward Voltage vs. Forward Current

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



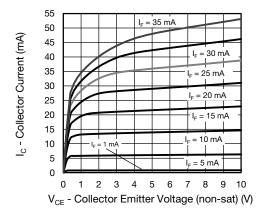


Fig. 6 - Collector Current vs. Collector Emitter Voltage

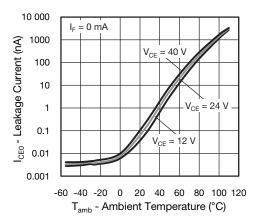


Fig. 7 - Leakage Current vs. Ambient Temperature

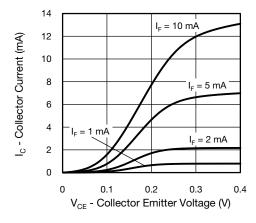


Fig. 8 - Collector Current vs. Collector Emitter Voltage

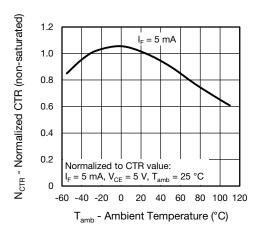


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

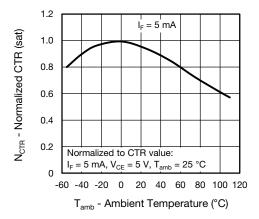


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

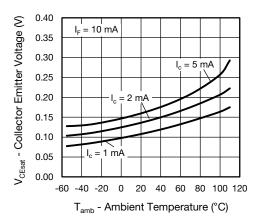


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

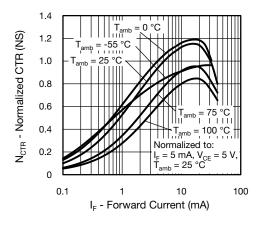


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current

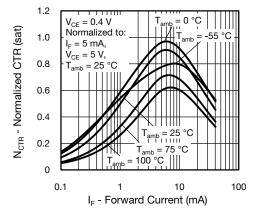


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

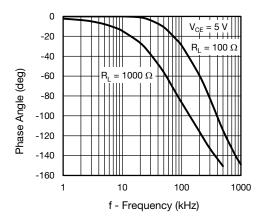


Fig. 14 - F_{CTR} vs. Phase Angle

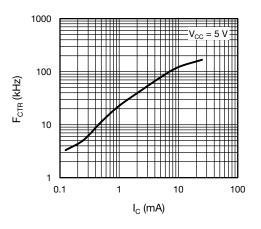


Fig. 15 - F_{CTR} vs. Collector Current

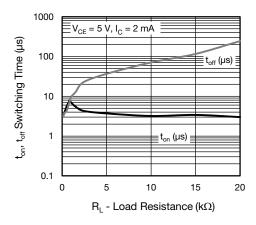
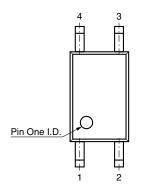
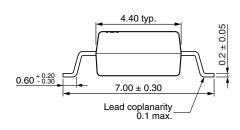


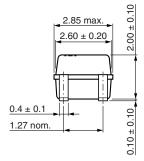
Fig. 16 - Switching Time vs. Load Resistance

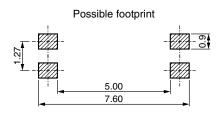


PACKAGE DIMENSIONS in millimeters

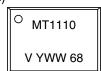








PACKAGE MARKING (example of TCMT1110)



PACKAGING INFORMATION (TAPE AND REEL) in millimeters

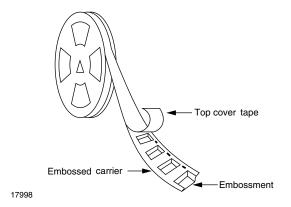


Fig. 17 - Tape and Reel Shipping Medium

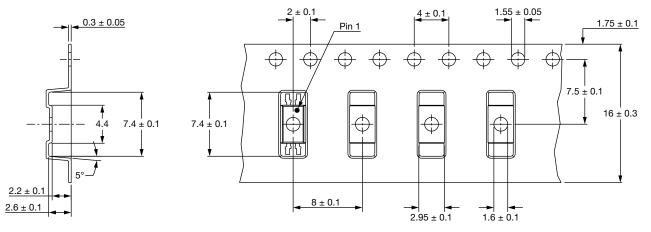


Fig. 18 - Tape and Reel Packing (3000 parts per reel)

SOLDER PROFILES

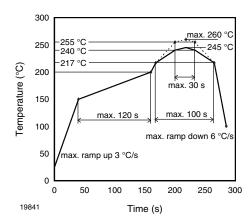


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.